



AiP74HC/HCT153 Dual 4-input Multiplexer

Product Specification

Specification Revision History:

Version	Date	Description
2012-06-A1	2012-06	New
2021-11-A2	2021-11	Modify Ordering Information; Modify ambient temperature to -40°C $\sim +105^{\circ}\text{C}$ and add electrical characteristics of -40°C $\sim +105^{\circ}\text{C}$
2021-12-A3	2021-12	Modify Ordering Information



1、 General Description

The AiP74HC/HCT153 is a dual 4-input multiplexer. The device features independent enable inputs (\bar{nE}) and common data select inputs (S0 and S1). For each multiplexer, the select inputs select one of the four binary inputs and routes it to the multiplexer output (nY). A HIGH on \bar{E} forces the corresponding multiplexer outputs LOW. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} .

Features:

- Input levels:
 - For AiP74HC153: CMOS level
 - For AiP74HCT153: TTL level
- Non-inverting outputs
- Separate enable input for each output
- Common select inputs
- Permits multiplexing from n lines to 1 line
- Enable line provided for cascading (n lines to 1 line)
- Specified from -40°C to +105°C
- Packaging information: DIP16/SOP16/TSSOP16

**Ordering Information:****Tube packing specifications:**

Part number	Packaging form	Marking code	Tube quantity	Boxed tube quantity	Boxed quantity	Notes
AiP74HC153DA16.TB	DIP16	74HC153	25 PCS/tube	40 tube/box	1000 PCS/box	Dimensions of plastic enclosure: 19.0mm×6.4mm Pin spacing: 2.54mm
AiP74HCT153DA16.TB	DIP16	74HCT153	25 PCS/tube	40 tube/box	1000 PCS/box	Dimensions of plastic enclosure: 19.0mm×6.4mm Pin spacing: 2.54mm
AiP74HC153SA16.TB	SOP16	74HC153	50 PCS/tube	200 tube/box	10000 PCS/box	Dimensions of plastic enclosure: 10.0mm×3.9mm Pin spacing: 1.27mm
AiP74HCT153SA16.TB	SOP16	74HCT153	50 PCS/tube	200 tube/box	10000 PCS/box	Dimensions of plastic enclosure: 10.0mm×3.9mm Pin spacing: 1.27mm
AiP74HC153TA16.TB	TSSOP16	74HC153	96 PCS/tube	200 tube/box	19200 PCS/box	Dimensions of plastic enclosure: 5.0mm×4.4mm Pin spacing: 0.65mm
AiP74HCT153TA16.TB	TSSOP16	74HCT153	96 PCS/tube	200 tube/box	19200 PCS/box	Dimensions of plastic enclosure: 5.0mm×4.4mm Pin spacing: 0.65mm

**Reel packing specifications:**

Part number	Packaging form	Marking code	Reel quantity	Boxed reel quantity	Notes
AiP74HC153SA16.TR	SOP16	74HC153	4000 PCS/reel	8000 PCS/box	Dimensions of plastic enclosure: 10.0mm×3.9mm Pin spacing:1.27mm
AiP74HCT153SA16.TR	SOP16	74HCT153	4000 PCS/reel	8000 PCS/box	Dimensions of plastic enclosure: 10.0mm×3.9mm Pin spacing:1.27mm
AiP74HC153TA16.TR	TSSOP16	74HC153	5000 PCS/reel	10000 PCS/box	Dimensions of plastic enclosure: 5.0mm×4.4mm Pin spacing:0.65mm
AiP74HCT153TA16.TR	TSSOP16	74HCT153	5000 PCS/reel	10000 PCS/box	Dimensions of plastic enclosure: 5.0mm×4.4mm Pin spacing:0.65mm

Note: If the physical information is inconsistent with the ordering information, please refer to the actual product.



2、Block Diagram And Pin Description

2.1、Block Diagram

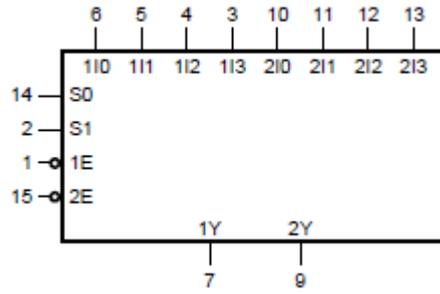


Figure 1. Logic symbol

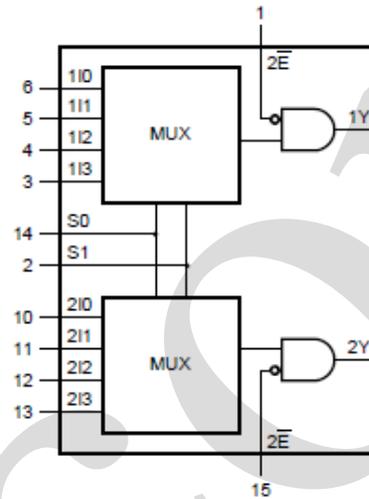


Figure 2. Functional diagram

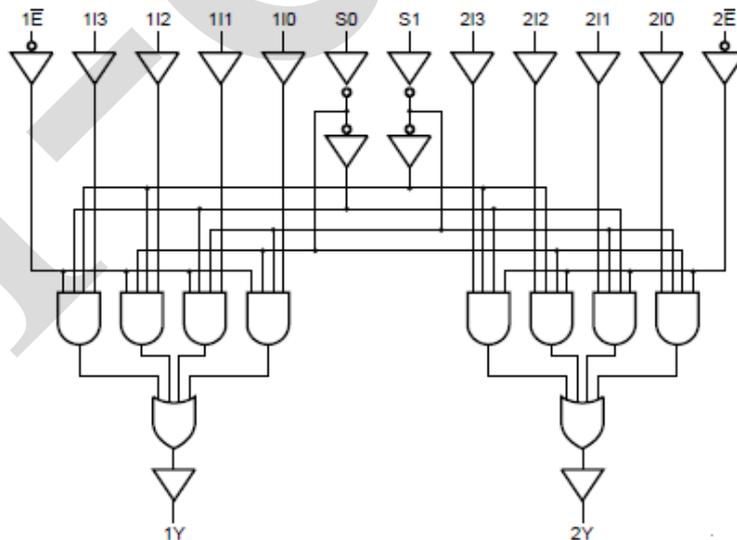
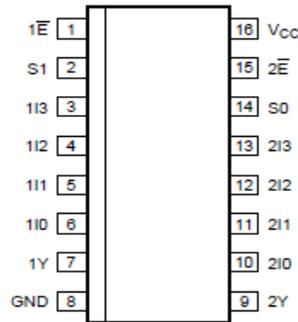


Figure 3. Logic diagram



2.2、Pin Configurations



2.3、Pin Description

Pin No.	Pin Name	Description
1	$\overline{1E}$	output enable input (active LOW)
2	S1	data select input
3	I13	data input source 1
4	I12	data input source 1
5	I11	data input source 1
6	I10	data input source 1
7	1Y	multiplexer output source 1
8	GND	ground (0V)
9	2Y	multiplexer output source 2
10	2I0	data input source 2
11	2I1	data input source 2
12	2I2	data input source 2
13	2I3	data input source 2
14	S0	data select input
15	$\overline{2E}$	output enable input (active LOW)
16	V _{cc}	supply voltage

2.4、Function Table

Select Input		Input				Output Enable	Output
S0	S1	nI0	nI1	nI2	nI3	\overline{nE}	nY
X	X	X	X	X	X	H	L
L	L	L	X	X	X	L	L
L	L	H	X	X	X	L	H
H	L	X	L	X	X	L	L
H	L	X	H	X	X	L	H
L	H	X	X	L	X	L	L
L	H	X	X	H	X	L	H
H	H	X	X	X	L	L	L
H	H	X	X	X	H	L	H

Note: H=HIGH voltage level; L=LOW voltage level; X=don't care.



3、Electrical Parameter

3.1、Absolute Maximum Ratings

(Voltages are referenced to GND(ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Max.	Unit
supply voltage	V_{CC}	-	-0.5	+7.0	V
input clamping current	I_{IK}	$V_I < -0.5V$ or $V_I > V_{CC}+0.5V$	-	± 20	mA
output clamping current	I_{OK}	$V_O < -0.5V$ or $V_O > V_{CC}+0.5V$	-	± 20	mA
output current	I_O	$-0.5V < V_O < V_{CC}+0.5V$	-	± 25	mA
supply current	I_{CC}	-	-	50	mA
ground current	I_{GND}	-	-50	-	mA
storage temperature	T_{stg}	-	-65	+150	$^{\circ}C$
total power dissipation	P_{tot}	-	-	500	mW
soldering temperature	T_L	10s	DIP	245	$^{\circ}C$
			SOP	250	

Note:

[1] For DIP16 packages: above $70^{\circ}C$ the value of P_{tot} derates linearly with 12mW/K.

[2] For SOP16 packages: above $70^{\circ}C$ the value of P_{tot} derates linearly with 8mW/K.

[3] For (T)SSOP16 packages: above $60^{\circ}C$ the value of P_{tot} derates linearly with 5.5mW/K.

3.2、Recommended Operating Conditions

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
AiP74HC153						
supply voltage	V_{CC}	-	2.0	5.0	6.0	V
input voltage	V_I	-	0	-	V_{CC}	V
output voltage	V_O	-	0	-	V_{CC}	V
input transition rise and fall rate	$\Delta t/\Delta V$	$V_{CC}=2.0V$	-	-	625	ns/V
		$V_{CC}=4.5V$	-	1.67	139	ns/V
		$V_{CC}=6.0V$	-	-	83	ns/V
ambient temperature	T_{amb}	-	-40	-	+105	$^{\circ}C$
AiP74HCT153						
supply voltage	V_{CC}	-	4.5	5.0	5.5	V
input voltage	V_I	-	0	-	V_{CC}	V
output voltage	V_O	-	0	-	V_{CC}	V
input transition rise and fall rate	$\Delta t/\Delta V$	$V_{CC}=4.5V$	-	1.67	139	ns/V
ambient temperature	T_{amb}	-	-40	-	+105	$^{\circ}C$



3.3、Electrical Characteristics

3.3.1、DC Characteristics 1

($T_{amb}=25^{\circ}\text{C}$, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	
AiP74HC153							
HIGH-level input voltage	V_{IH}	$V_{CC}=2.0\text{V}$	1.5	1.2	-	V	
		$V_{CC}=4.5\text{V}$	3.15	2.4	-	V	
		$V_{CC}=6.0\text{V}$	4.2	3.2	-	V	
LOW-level input voltage	V_{IL}	$V_{CC}=2.0\text{V}$	-	0.8	0.5	V	
		$V_{CC}=4.5\text{V}$	-	2.1	1.35	V	
		$V_{CC}=6.0\text{V}$	-	2.8	1.8	V	
HIGH-level output voltage	V_{OH}	$V_I=V_{IH}$ or V_{IL}	$I_O=-20\mu\text{A}; V_{CC}=2.0\text{V}$	1.9	2.0	-	V
			$I_O=-20\mu\text{A}; V_{CC}=4.5\text{V}$	4.4	4.5	-	V
			$I_O=-20\mu\text{A}; V_{CC}=6.0\text{V}$	5.9	6.0	-	V
			$I_O=-4.0\text{mA}; V_{CC}=4.5\text{V}$	3.98	4.32	-	V
			$I_O=-5.2\text{mA}; V_{CC}=6.0\text{V}$	5.48	5.81	-	V
LOW-level output voltage	V_{OL}	$V_I=V_{IH}$ or V_{IL}	$I_O=20\mu\text{A}; V_{CC}=2.0\text{V}$	-	0	0.1	V
			$I_O=20\mu\text{A}; V_{CC}=4.5\text{V}$	-	0	0.1	V
			$I_O=20\mu\text{A}; V_{CC}=6.0\text{V}$	-	0	0.1	V
			$I_O=4.0\text{mA}; V_{CC}=4.5\text{V}$	-	0.15	0.26	V
			$I_O=5.2\text{mA}; V_{CC}=6.0\text{V}$	-	0.16	0.26	V
input leakage current	I_I	$V_I=V_{CC}$ or GND; $V_{CC}=6.0\text{V}$	-	-	± 0.1	μA	
supply current	I_{CC}	$V_I=V_{CC}$ or GND; $I_O=0\text{A}; V_{CC}=6.0\text{V}$	-	-	8.0	μA	
input capacitance	C_I	-	-	3.5	-	pF	
AiP74HCT153							
HIGH-level input voltage	V_{IH}	$V_{CC}=4.5\text{V}$ to 5.5V	2.0	1.6	-	V	
LOW-level input voltage	V_{IL}	$V_{CC}=4.5\text{V}$ to 5.5V	-	1.2	0.8	V	
HIGH-level output voltage	V_{OH}	$V_I=V_{IH}$ or $V_{IL}; V_{CC}=4.5\text{V}$	$I_O=-20\mu\text{A}$	4.4	4.5	-	V
			$I_O=-4.0\text{mA}$	3.98	4.32	-	V
LOW-level output voltage	V_{OL}	$V_I=V_{IH}$ or V_{IL}	$I_O=20\mu\text{A}; V_{CC}=4.5\text{V}$	-	0	0.1	V
			$I_O=5.2\text{mA}; V_{CC}=6.0\text{V}$	-	0.15	0.26	V
input leakage current	I_I	$V_I=V_{CC}$ or GND; $V_{CC}=5.5\text{V}$	-	-	± 0.1	μA	
supply current	I_{CC}	$V_I=V_{CC}$ or GND; $I_O=0\text{A}; V_{CC}=5.5\text{V}$	-	-	8.0	μA	
additional supply current	ΔI_{CC}	$V_I=V_{CC}-2.1\text{V};$ other inputs at V_{CC} or GND; $I_O=0\text{A};$ $V_{CC}=4.5\text{V}$ to 5.5V	1In, 2In	-	45	162	μA
			nE	-	60	216	μA
			Sn	-	135	486	μA
input capacitance	C_I	-	-	3.5	-	pF	



3.3.2、DC Characteristics 2

($T_{amb} = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	
AiP74HC153							
HIGH-level input voltage	V_{IH}	$V_{CC}=2.0\text{V}$	1.5	-	-	V	
		$V_{CC}=4.5\text{V}$	3.15	-	-	V	
		$V_{CC}=6.0\text{V}$	4.2	-	-	V	
LOW-level input voltage	V_{IL}	$V_{CC}=2.0\text{V}$	-	-	0.5	V	
		$V_{CC}=4.5\text{V}$	-	-	1.35	V	
		$V_{CC}=6.0\text{V}$	-	-	1.8	V	
HIGH-level output voltage	V_{OH}	$V_I = V_{IH}$ or V_{IL}	$I_O = -20\mu\text{A}; V_{CC} = 2.0\text{V}$	1.9	-	-	V
			$I_O = -20\mu\text{A}; V_{CC} = 4.5\text{V}$	4.4	-	-	V
			$I_O = -20\mu\text{A}; V_{CC} = 6.0\text{V}$	5.9	-	-	V
			$I_O = -4.0\text{mA}; V_{CC} = 4.5\text{V}$	3.84	-	-	V
			$I_O = -5.2\text{mA}; V_{CC} = 6.0\text{V}$	5.34	-	-	V
LOW-level output voltage	V_{OL}	$V_I = V_{IH}$ or V_{IL}	$I_O = 20\mu\text{A}; V_{CC} = 2.0\text{V}$	-	-	0.1	V
			$I_O = 20\mu\text{A}; V_{CC} = 4.5\text{V}$	-	-	0.1	V
			$I_O = 20\mu\text{A}; V_{CC} = 6.0\text{V}$	-	-	0.1	V
			$I_O = 4.0\text{mA}; V_{CC} = 4.5\text{V}$	-	-	0.33	V
			$I_O = 5.2\text{mA}; V_{CC} = 6.0\text{V}$	-	-	0.33	V
input leakage current	I_I	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0\text{V}$	-	-	± 1.0	μA	
supply current	I_{CC}	$V_I = V_{CC}$ or GND; $I_O = 0\text{A}; V_{CC} = 6.0\text{V}$	-	-	80	μA	
AiP74HCT153							
HIGH-level input voltage	V_{IH}	$V_{CC} = 4.5\text{V}$ to 5.5V	2.0	-	-	V	
LOW-level input voltage	V_{IL}	$V_{CC} = 4.5\text{V}$ to 5.5V	-	-	0.8	V	
HIGH-level output voltage	V_{OH}	$V_I = V_{IH}$ or $V_{IL}; V_{CC} = 4.5\text{V}$	$I_O = -20\mu\text{A}$	4.4	-	-	V
			$I_O = -4.0\text{mA}$	3.84	-	-	V
LOW-level output voltage	V_{OL}	$V_I = V_{IH}$ or V_{IL}	$I_O = 20\mu\text{A}; V_{CC} = 4.5\text{V}$	-	-	0.1	V
			$I_O = 5.2\text{mA}; V_{CC} = 6.0\text{V}$	-	-	0.33	V
input leakage current	I_I	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5\text{V}$	-	-	± 1.0	μA	
supply current	I_{CC}	$V_I = V_{CC}$ or GND; $I_O = 0\text{A}; V_{CC} = 5.5\text{V}$	-	-	80	μA	
additional supply current	ΔI_{CC}	$V_I = V_{CC} - 2.1\text{V};$ other inputs at V_{CC} or GND; $I_O = 0\text{A};$ $V_{CC} = 4.5\text{V}$ to 5.5V	1In, 2In	-	-	203	μA
			$\bar{n}\bar{E}$	-	-	270	μA
			Sn	-	-	608	μA



3.3.3、DC Characteristics 3

($T_{amb} = -40^{\circ}\text{C}$ to $+105^{\circ}\text{C}$, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	
AiP74HC153							
HIGH-level input voltage	V_{IH}	$V_{CC}=2.0\text{V}$	1.5	-	-	V	
		$V_{CC}=4.5\text{V}$	3.15	-	-	V	
		$V_{CC}=6.0\text{V}$	4.2	-	-	V	
LOW-level input voltage	V_{IL}	$V_{CC}=2.0\text{V}$	-	-	0.5	V	
		$V_{CC}=4.5\text{V}$	-	-	1.35	V	
		$V_{CC}=6.0\text{V}$	-	-	1.8	V	
HIGH-level output voltage	V_{OH}	$V_I = V_{IH} \text{ or } V_{IL}$	$I_O = -20\mu\text{A}; V_{CC} = 2.0\text{V}$	1.9	-	-	V
			$I_O = -20\mu\text{A}; V_{CC} = 4.5\text{V}$	4.4	-	-	V
			$I_O = -20\mu\text{A}; V_{CC} = 6.0\text{V}$	5.9	-	-	V
			$I_O = -4.0\text{mA}; V_{CC} = 4.5\text{V}$	3.7	-	-	V
			$I_O = -5.2\text{mA}; V_{CC} = 6.0\text{V}$	5.2	-	-	V
LOW-level output voltage	V_{OL}	$V_I = V_{IH} \text{ or } V_{IL}$	$I_O = 20\mu\text{A}; V_{CC} = 2.0\text{V}$	-	-	0.1	V
			$I_O = 20\mu\text{A}; V_{CC} = 4.5\text{V}$	-	-	0.1	V
			$I_O = 20\mu\text{A}; V_{CC} = 6.0\text{V}$	-	-	0.1	V
			$I_O = 4.0\text{mA}; V_{CC} = 4.5\text{V}$	-	-	0.4	V
			$I_O = 5.2\text{mA}; V_{CC} = 6.0\text{V}$	-	-	0.4	V
input leakage current	I_I	$V_I = V_{CC} \text{ or } \text{GND}; V_{CC} = 6.0\text{V}$	-	-	± 1.0	μA	
supply current	I_{CC}	$V_I = V_{CC} \text{ or } \text{GND}; I_O = 0\text{A}; V_{CC} = 6.0\text{V}$	-	-	160	μA	
AiP74HCT153							
HIGH-level input voltage	V_{IH}	$V_{CC} = 4.5\text{V to } 5.5\text{V}$	2.0	-	-	V	
LOW-level input voltage	V_{IL}	$V_{CC} = 4.5\text{V to } 5.5\text{V}$	-	-	0.8	V	
HIGH-level output voltage	V_{OH}	$V_I = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5\text{V}$	$I_O = -20\mu\text{A}$	4.4	-	-	V
			$I_O = -4.0\text{mA}$	3.7	-	-	V
LOW-level output voltage	V_{OL}	$V_I = V_{IH} \text{ or } V_{IL}$	$I_O = 20\mu\text{A}; V_{CC} = 4.5\text{V}$	-	-	0.1	V
			$I_O = 5.2\text{mA}; V_{CC} = 6.0\text{V}$	-	-	0.4	V
input leakage current	I_I	$V_I = V_{CC} \text{ or } \text{GND}; V_{CC} = 5.5\text{V}$	-	-	± 1.0	μA	
supply current	I_{CC}	$V_I = V_{CC} \text{ or } \text{GND}; I_O = 0\text{A}; V_{CC} = 5.5\text{V}$	-	-	160	μA	
additional supply current	ΔI_{CC}	$V_I = V_{CC} - 2.1\text{V};$ other inputs at V_{CC} or GND; $I_O = 0\text{A};$ $V_{CC} = 4.5\text{V to } 5.5\text{V}$	1In, 2In	-	-	221	μA
			$\bar{n}\bar{E}$	-	-	294	μA
			Sn	-	-	662	μA



3.3.4. AC Characteristics 1

($T_{amb}=25^{\circ}C$, $GND=0V$, $t_r=t_f=6ns$; $C_L=50pF$, unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	
AiP74HC153							
propagation delay	t_{pd}	1In to nY, 2In to nY; see Figure 5 ^[1]	$V_{CC}=2.0V$	-	47	145	ns
			$V_{CC}=4.5V$	-	17	29	ns
			$V_{CC}=5.0V$; $C_L=15pF$	-	14	-	ns
			$V_{CC}=6.0V$	-	14	25	ns
		Sn to nY; see Figure 6	$V_{CC}=2.0V$	-	50	150	ns
			$V_{CC}=4.5V$	-	18	30	ns
			$V_{CC}=5.0V$; $C_L=15pF$	-	15	-	ns
			$V_{CC}=6.0V$	-	14	26	ns
		$\bar{n}E$ to nY; see Figure 6	$V_{CC}=2.0V$	-	33	100	ns
			$V_{CC}=4.5V$	-	12	20	ns
			$V_{CC}=5.0V$; $C_L=15pF$	-	10	-	ns
			$V_{CC}=6.0V$	-	10	17	ns
transition time	t_t	see Figure 5 ^[2]	$V_{CC}=2.0V$	-	19	75	ns
			$V_{CC}=4.5V$	-	7	15	ns
			$V_{CC}=6.0V$	-	6	13	ns
power dissipation capacitance	C_{PD}	per package; $V_I=GND$ to V_{CC} ^[3]	-	30	-	pF	
AiP74HCT153							
HIGH to LOW propagation delay	t_{PHL}	1In to nY, 2In to nY; see Figure 5 ^[1]	$V_{CC}=4.5V$	-	19	34	ns
			$V_{CC}=5.0V$; $C_L=15pF$	-	16	-	ns
LOW to HIGH propagation delay	t_{PLH}	1In to nY, 2In to nY; see Figure 5	$V_{CC}=4.5V$	-	13	24	ns
			$V_{CC}=5.0V$; $C_L=15pF$	-	16	-	ns
propagation delay	t_{pd}	Sn to nY; see Figure 6	$V_{CC}=4.5V$	-	20	34	ns
			$V_{CC}=5.0V$; $C_L=15pF$	-	17	-	ns
		$\bar{n}E$ to nY; see Figure 6	$V_{CC}=4.5V$	-	14	27	ns
			$V_{CC}=5.0V$; $C_L=15pF$	-	11	-	ns
transition time	t_t	$V_{CC}=4.5V$; see Figure 5 ^[2]	-	7	15	ns	
power dissipation capacitance	C_{PD}	per package; $V_I=GND$ to $V_{CC}-1.5V$ ^[3]	-	30	-	pF	

Note:

[1] t_{pd} is the same as t_{PLH} and t_{PHL} .

[2] t_t is the same as t_{THL} and t_{TLH} .

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in uW).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$$

f_i =input frequency in MHz; f_o =output frequency in MHz;

C_L =output load capacitance in pF;

V_{CC} =supply voltage in V;

N =number of inputs switching;

$\sum (C_L \times V_{CC}^2 \times f_o)$ =sum of outputs.



3.3.5、 AC Characteristics 2

($T_{amb} = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, $GND=0\text{V}$, $t_r=t_f=6\text{ns}$; $C_L=50\text{pF}$, unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	
AiP74HC153							
propagation delay	t_{pd}	1In to nY, 2In to nY; see Figure 5 ^[1]	$V_{CC}=2.0\text{V}$	-	-	180	ns
			$V_{CC}=4.5\text{V}$	-	-	36	ns
			$V_{CC}=6.0\text{V}$	-	-	31	ns
		Sn to nY; see Figure 6	$V_{CC}=2.0\text{V}$	-	-	190	ns
			$V_{CC}=4.5\text{V}$	-	-	38	ns
			$V_{CC}=6.0\text{V}$	-	-	33	ns
		\bar{nE} to nY; see Figure 6	$V_{CC}=2.0\text{V}$	-	-	125	ns
			$V_{CC}=4.5\text{V}$	-	-	25	ns
			$V_{CC}=6.0\text{V}$	-	-	21	ns
transition time	t_t	see Figure 5 ^[2]	$V_{CC}=2.0\text{V}$	-	-	95	ns
			$V_{CC}=4.5\text{V}$	-	-	19	ns
			$V_{CC}=6.0\text{V}$	-	-	16	ns
AiP74HCT153							
HIGH to LOW propagation delay	t_{PHL}	1In to nY, 2In to nY; see Figure 5 ^[1]	$V_{CC}=4.5\text{V}$	-	-	43	ns
LOW to HIGH propagation delay	t_{PLH}	1In to nY, 2In to nY; see Figure 5	$V_{CC}=4.5\text{V}$	-	-	30	ns
propagation delay	t_{pd}	Sn to nY; see Figure 6	$V_{CC}=4.5\text{V}$	-	-	43	ns
		\bar{nE} to nY; see Figure 6	$V_{CC}=4.5\text{V}$	-	-	34	ns
transition time	t_t	$V_{CC}=4.5\text{V}$; see Figure 5 ^[2]		-	-	19	ns

Note:

[1] t_{pd} is the same as t_{PLH} and t_{PHL} .

[2] t_t is the same as t_{THL} and t_{TLH} .



3.3.6、 AC Characteristics 3

($T_{amb}=-40^{\circ}\text{C}$ to $+105^{\circ}\text{C}$, $\text{GND}=0\text{V}$, $t_r=t_f=6\text{ns}$; $C_L=50\text{pF}$, unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	
AiP74HC153							
propagation delay	t_{pd}	1In to nY, 2In to nY; see Figure 5 ^[1]	$V_{CC}=2.0\text{V}$	-	-	220	ns
			$V_{CC}=4.5\text{V}$	-	-	44	ns
			$V_{CC}=6.0\text{V}$	-	-	38	ns
		Sn to nY; see Figure 6	$V_{CC}=2.0\text{V}$	-	-	225	ns
			$V_{CC}=4.5\text{V}$	-	-	45	ns
			$V_{CC}=6.0\text{V}$	-	-	38	ns
		\bar{nE} to nY; see Figure 6	$V_{CC}=2.0\text{V}$	-	-	150	ns
			$V_{CC}=4.5\text{V}$	-	-	30	ns
			$V_{CC}=6.0\text{V}$	-	-	26	ns
transition time	t_t	see Figure 5 ^[2]	$V_{CC}=2.0\text{V}$	-	-	110	ns
			$V_{CC}=4.5\text{V}$	-	-	22	ns
			$V_{CC}=6.0\text{V}$	-	-	19	ns
AiP74HCT153							
HIGH to LOW propagation delay	t_{PHL}	1In to nY, 2In to nY; see Figure 5 ^[1]	$V_{CC}=4.5\text{V}$	-	-	51	ns
LOW to HIGH propagation delay	t_{PLH}	1In to nY, 2In to nY; see Figure 5	$V_{CC}=4.5\text{V}$	-	-	36	ns
propagation delay	t_{pd}	Sn to nY; see Figure 6	$V_{CC}=4.5\text{V}$	-	-	51	ns
		\bar{nE} to nY; see Figure 6	$V_{CC}=4.5\text{V}$	-	-	41	ns
transition time	t_t	$V_{CC}=4.5\text{V}$; see Figure 5 ^[2]		-	-	22	ns

Note:

[1] t_{pd} is the same as t_{PLH} and t_{PHL} .

[2] t_t is the same as t_{THL} and t_{TLH} .



4、 Testing Circuit

4.1、 AC Testing Circuit

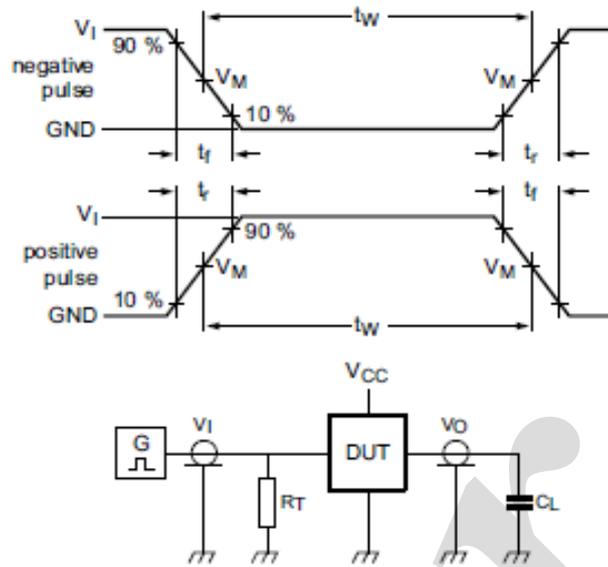


Figure 4. Test circuit for measuring switching times

Definitions for test circuit:

C_L =Load capacitance including jig and probe capacitance.

R_T =Termination resistance should be equal to the output impedance Z_o of the pulse generator.

4.2、 AC Testing Waveforms

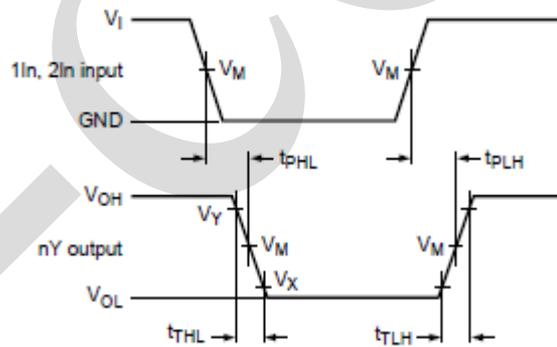


Figure 5. Waveforms showing the input (1In, 2In) to output (1Y, 2Y) propagation delays and output transition times

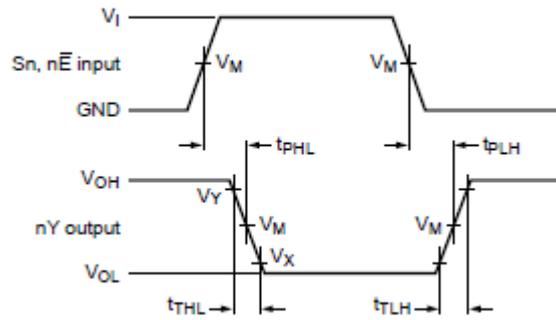


Figure 6. Waveforms showing the input (Sn, nE) to output (nY) propagation delays

4.3. Measurement Points

Type	Input		Output	
	V_M	V_M	V_X	V_Y
AiP74HC153	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	$0.1 \times V_{CC}$	$0.9 \times V_{CC}$
AiP74HCT153	1.3V	1.3V	$0.1 \times V_{CC}$	$0.9 \times V_{CC}$

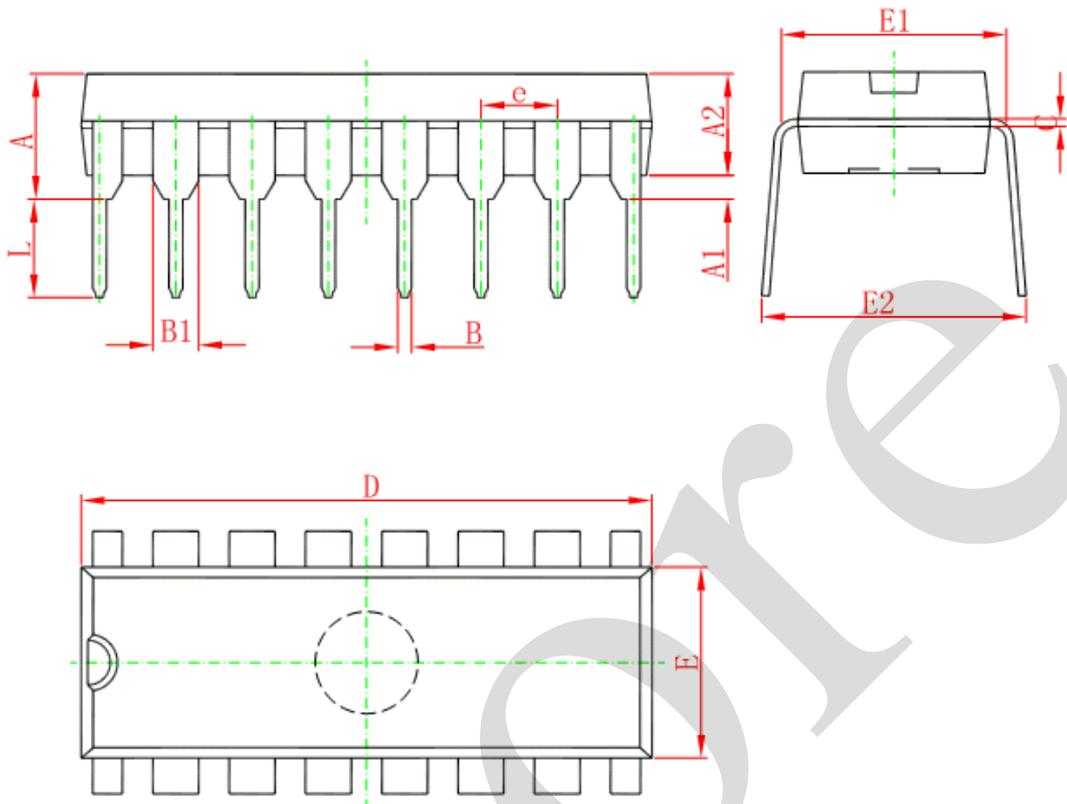
4.4. Test Data

Type	Input		Load	Test
	V_I	t_r, t_f	C_L	
AiP74HC153	V_{CC}	6ns	15pF, 50pF	t_{PHL}, t_{PLH}
AiP74HCT153	3V	6ns	15pF, 50pF	t_{PHL}, t_{PLH}



5、Package Information

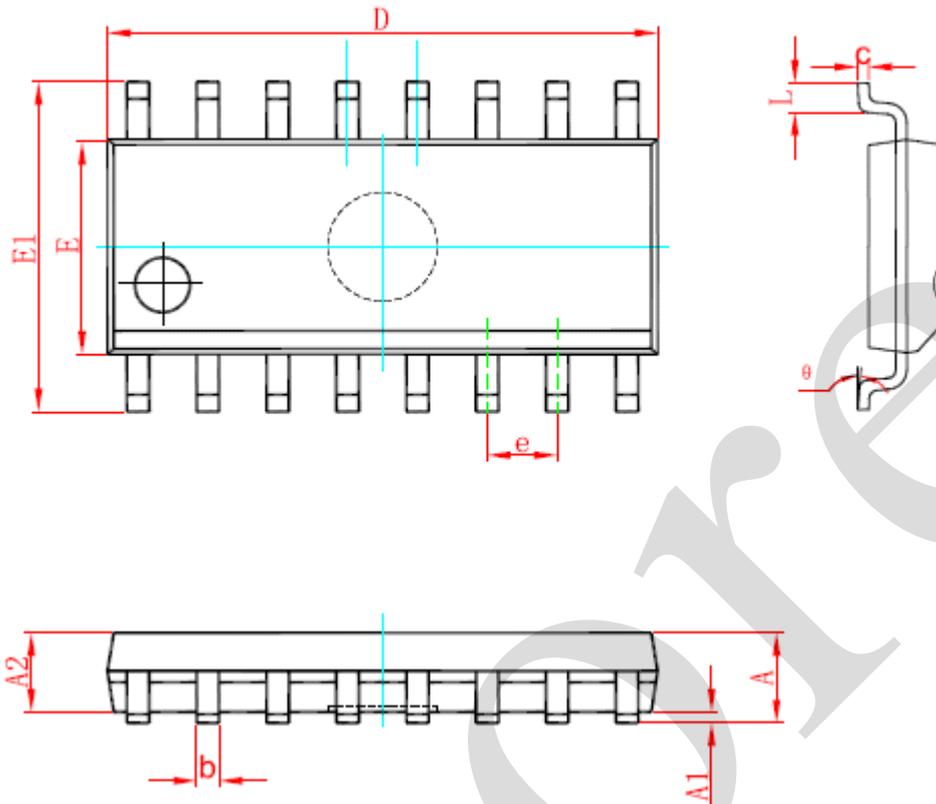
5.1、DIP16



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	3.710	4.310	0.146	0.170
A1	0.510		0.020	
A2	3.200	3.600	0.126	0.142
B	0.380	0.570	0.015	0.022
B1	1.524 (BSC)		0.060 (BSC)	
C	0.204	0.360	0.008	0.014
D	18.800	19.200	0.740	0.756
E	6.200	6.600	0.244	0.260
E1	7.320	7.920	0.288	0.312
e	2.540 (BSC)		0.100 (BSC)	
L	3.000	3.600	0.118	0.142
E2	8.400	9.000	0.331	0.354



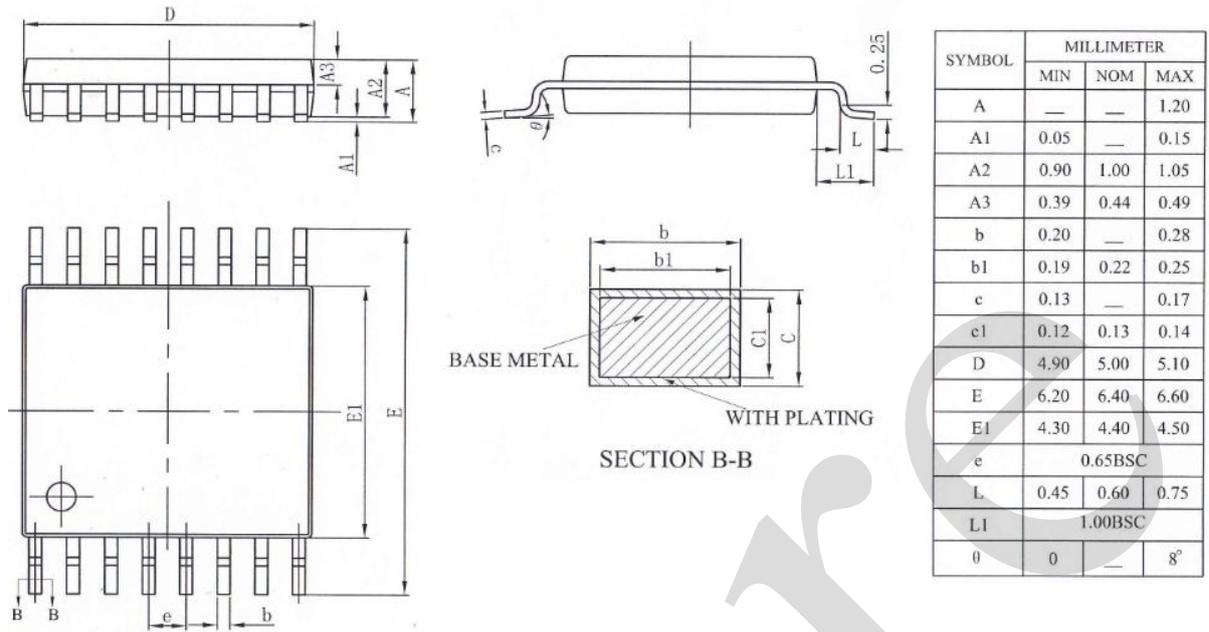
5.2、SOP16



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.007	0.010
D	9.800	10.200	0.386	0.402
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.270 (BSC)		0.050 (BSC)	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°



5.3、TSSOP16





6、 Statements And Notes

6.1、 The name and content of Hazardous substances or Elements in the product

Part name	Hazardous substances or Elements									
	Lead and lead compounds	Mercury and mercury compounds	Cadmium and cadmium compounds	Hexavalent chromium compounds	Polybrominated biphenyls	Polybrominated biphenyl ethers	Dibutyl phthalate	Butylbenzyl phthalate	Di-2-ethylhexyl phthalate	Diisobutyl phthalate
Lead frame	○	○	○	○	○	○	○	○	○	○
Plastic resin	○	○	○	○	○	○	○	○	○	○
Chip	○	○	○	○	○	○	○	○	○	○
The lead	○	○	○	○	○	○	○	○	○	○
Plastic sheet installed	○	○	○	○	○	○	○	○	○	○
explanation	○: Indicates that the content of hazardous substances or elements in the detection limit of the following the SJ/T11363-2006 standard. ×: Indicates that the content of hazardous substances or elements exceeding the SJ/T11363-2006 Standard limit requirements.									

6.2、 Notion

Recommended carefully reading this information before the use of this product;

The information in this document are subject to change without notice;

This information is using to the reference only, the company is not responsible for any loss;

The company is not responsible for the any infringement of the third party patents or other rights of the responsibility.